

TOSHIBA Field Effect Transistor Silicon P Channel Junction Type

2SJ105

For Audio Amplifier, Analog Switch, Constant Current and Impedance Converter Applications

Unit: mm

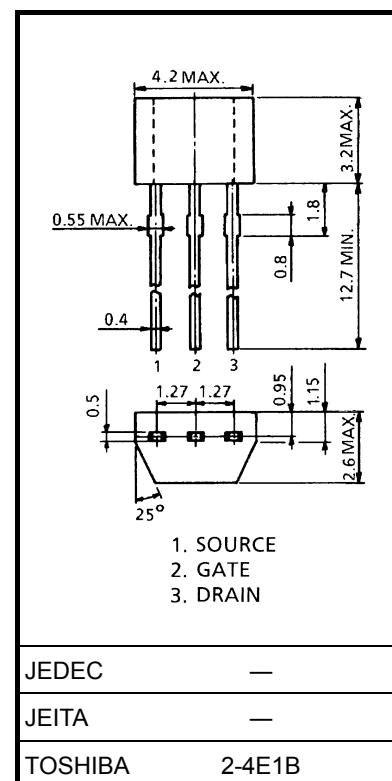
- High breakdown voltage: $V_{GDS} = 50$ V
- High input impedance: $I_{GSS} = 1.0$ nA (max) ($V_{GS} = 30$ V)
- Low $R_{DS(ON)}$: $R_{DS(ON)} = 270 \Omega$ (typ.) ($I_{DSS} = -5$ mA)
- Complimentary to 2SK330
- Small package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V_{GDS}	50	V
Gate current	I_G	-10	mA
Drain power dissipation	P_D	200	mW
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~125	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

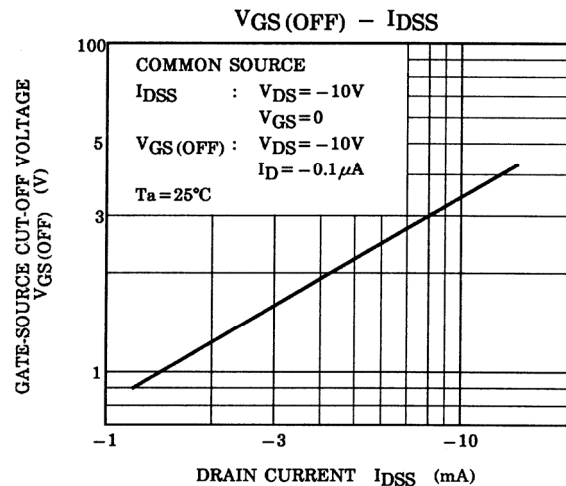
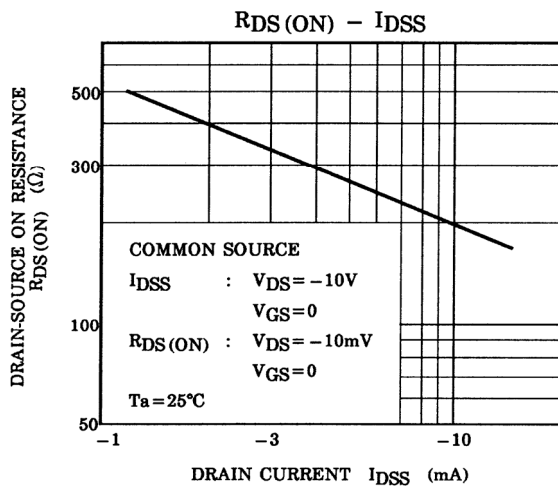
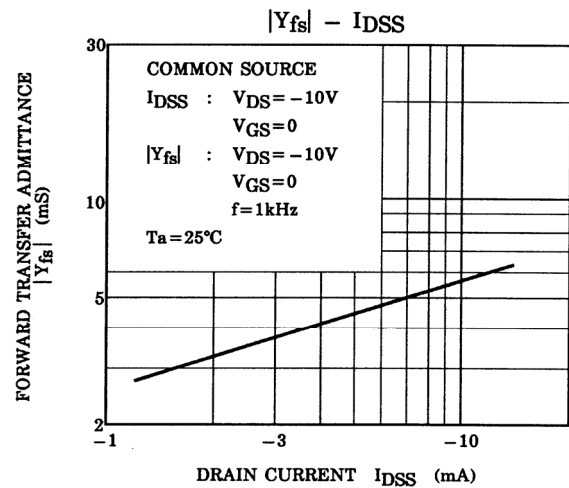
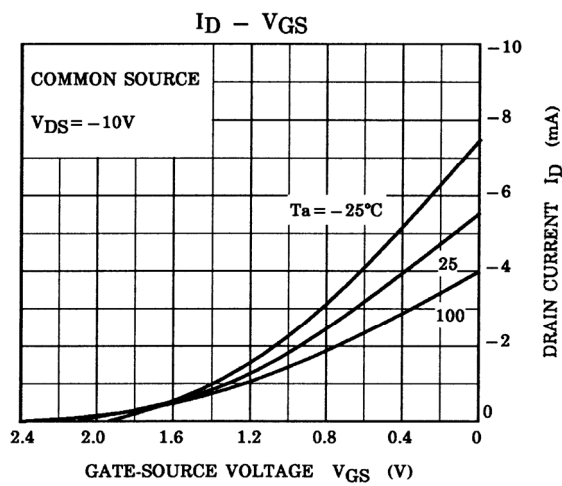
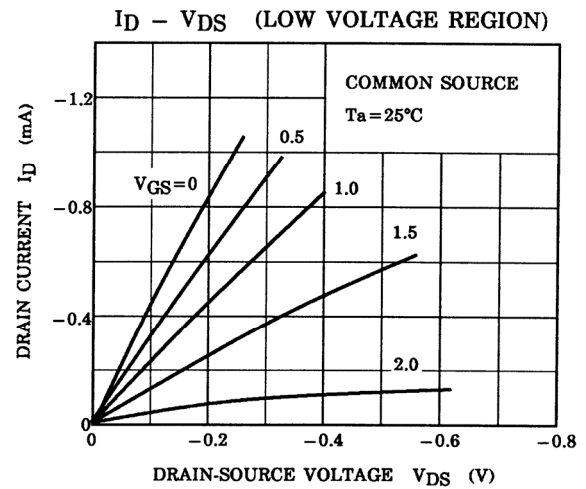
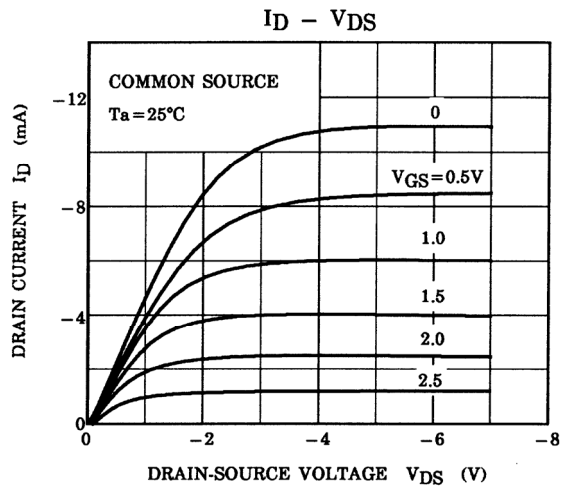


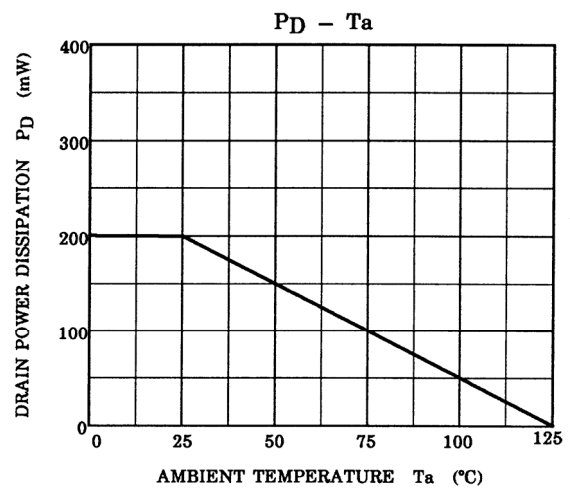
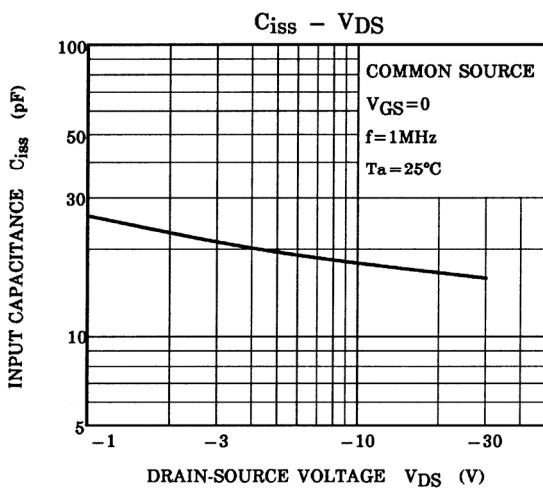
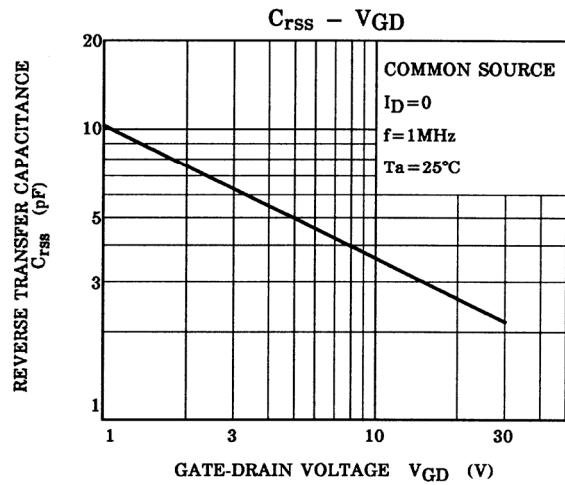
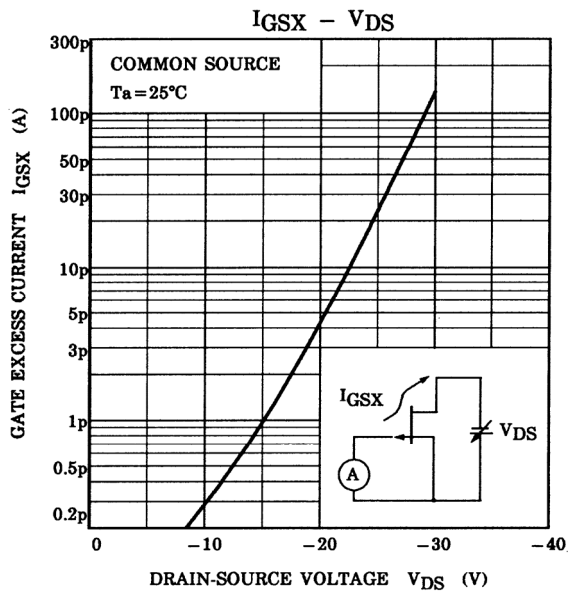
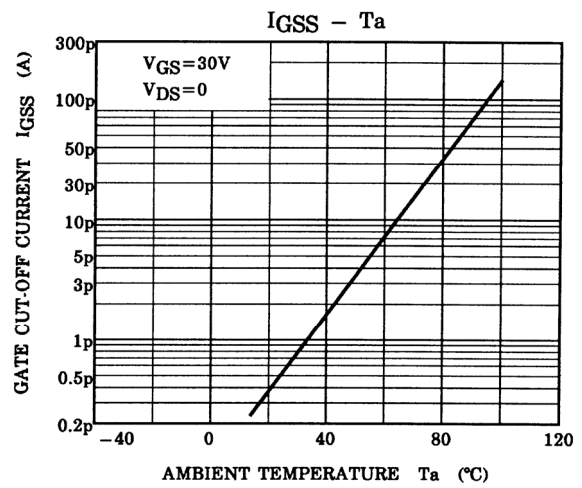
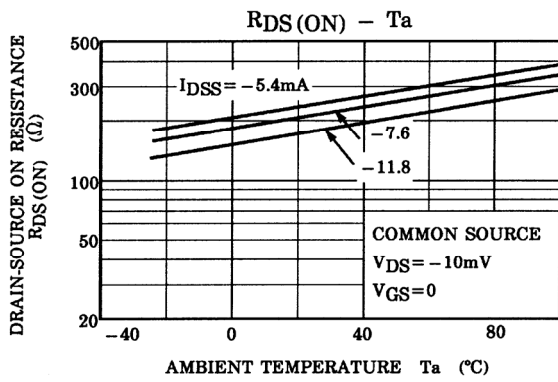
Weight: 0.13 g (typ.)

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate cut-off current	I_{GSS}	$V_{GS} = 30$ V, $V_{DS} = 0$	—	—	1.0	nA
Gate-drain breakdown voltage	$V_{(BR)GDS}$	$V_{DS} = 0$, $I_G = 100 \mu\text{A}$	50	—	—	V
Drain current	I_{DSS} (Note)	$V_{DS} = -10$ V, $V_{GS} = 0$	-1.2	—	-14	mA
Gate-source cut-off voltage	$V_{GS(OFF)}$	$V_{DS} = -10$ V, $I_D = -0.1 \mu\text{A}$	0.3	—	6.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -10$ V, $V_{GS} = 0$, $f = 1$ kHz	1.0	4.0	—	mS
Drain-source ON resistance	$R_{DS(ON)}$	$V_{DS} = -10$ mV, $V_{GS} = 0$ $I_{DSS} = -5$ mA	—	270	—	Ω
Input capacitance	C_{iss}	$V_{DS} = -10$ V, $V_{GS} = 0$, $f = 1$ MHz	—	18	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DG} = -10$ V, $I_D = 0$, $f = 1$ MHz	—	3.6	—	pF

Note: I_{DSS} classification Y: -1.2~-3.0 mA, GR: -2.6~-6.5 mA, BL: -6~-14 mA





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20070701-EN GENERAL

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